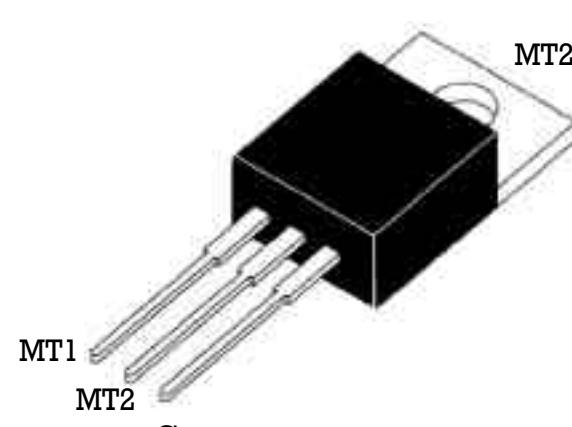


## LOGIC LEVEL TRIAC

<b>TO220-AB</b> 	<b>On-State Current</b> 12 Amp	<b>Gate Trigger Current</b> < 10 mA
	<b>Off-State Voltage</b> 200 V ÷ 600 V	
<p>This series of <b>TRIACs</b> uses a high performance PNPN technology.</p> <p>These parts are intended for general purpose AC switching applications with highly inductive loads.</p>		

### Absolute Maximum Ratings, according to IEC publication No. 134

SYMBOL	PARAMETER	CONDITIONS	Min.	Max.	Unit
$I_{T(RMS)}$	RMS On-state Current	Full sine wave, $T_C = 105^\circ C$	12		A
$I_{TSM}$	Non-repetitive On-State Current	Full Cycle, 60 Hz $t = 16.7 \text{ ms}$	125		A
$I_{TSM}$	Non-repetitive On-State Current	Full Cycle, 50 Hz $t = 20 \text{ ms}$	120		A
$I^2t$	Fusing Current	$t_p = 10 \text{ ms}$ , Half Cycle	80		$\text{A}^2\text{s}$
$I_{GM}$	Peak Gate Current	$20 \mu\text{s}$ max. $T_j = 125^\circ C$		4	A
$P_{G(AV)}$	Average Gate Power Dissipation	$T_j = 125^\circ C$		1	W
$di/dt$	Critical rate of rise of on-state current	$I_G = 2x I_{GT}$ , $t_r = 100\text{ns}$ $f = 120 \text{ Hz}$ , $T_j = 125^\circ C$	50		$\text{A}/\mu\text{s}$
$T_j$	Operating Temperature		-40	+125	$^\circ C$
$T_{stg}$	Storage Temperature		-40	+150	$^\circ C$

SYMBOL	PARAMETER	VOLTAGE			Unit
		B	D	M	
$V_{DRM}$	Repetitive Peak Off State Voltage	200	400	600	V
$V_{RRM}$					

## LOGIC LEVEL TRIAC

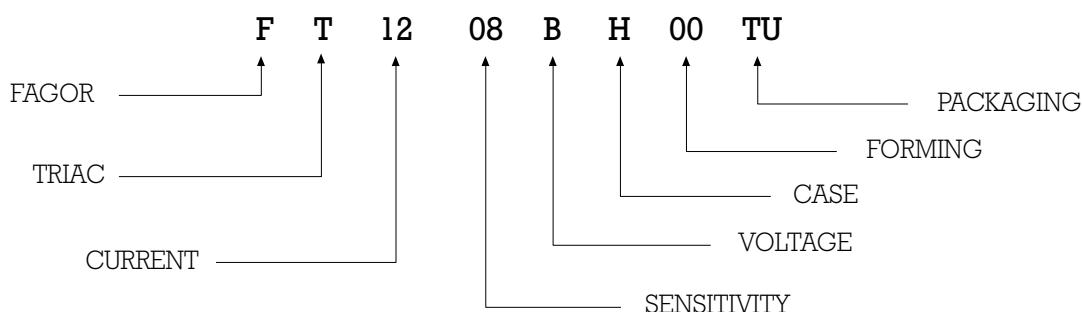
### Electrical Characteristics

SYMBOL	PARAMETER	CONDITIONS	Quadrant		SENSITIVITY	Unit
					08	
$I_{GT}^{(1)}$	Gate Trigger Current	$V_D = 12 \text{ V}_{DC}$ , $R_L = 30 \Omega$ , $T_j = 25^\circ\text{C}$	Q1÷Q3	MAX	10	mA
$I_{DRM} / I_{RRM}$	Off-State Leakage Current	$V_D = V_{DRM}$ , $R_{GK} = 1\text{K}$ , $T_j = 125^\circ\text{C}$ $V_R = V_{RRM}$ , $T_j = 25^\circ\text{C}$		MAX	1	mA
$V_{to}^{(2)}$	Threshold Voltage	$T_j = 125^\circ\text{C}$		MAX	0.85	V
$R_d^{(2)}$	Dynamic Resistance	$T_j = 125^\circ\text{C}$		MAX	35	m
$V_{TM}^{(2)}$	On-state Voltage	$I_T = 17 \text{ Amp}$ , $t_p = 380 \mu\text{s}$ , $T_j = 25^\circ\text{C}$		MAX	1.55	V
$V_{GT}$	Gate Trigger Voltage	$V_D = 12 \text{ V}_{DC}$ , $R_L = 30 \Omega$ , $T_j = 25^\circ\text{C}$	Q1÷Q3	MAX	1.3	V
$V_{GD}$	Gate Non Trigger Voltage	$V_D = V_{DRM}$ , $R_L = 3.3\text{K}$ , $T_j = 125^\circ\text{C}$	Q1÷Q3	MIN	0.2	V
$I_H^{(2)}$	Holding Current	$I_T = 100 \text{ mA}$ , Gate open, $T_j = 25^\circ\text{C}$		MAX	15	mA
$I_L$	Latching Current	$I_G = 1.2 I_{GT}$ , $T_j = 25^\circ\text{C}$	Q1,Q3 Q2	MAX	25 30	mA
$dv / dt^{(2)}$	Critical Rate of Voltage Rise	$V_D = 0.67 \times V_{DRM}$ , Gate open $T_j = 125^\circ\text{C}$		MIN	40	V/ $\mu$ s
$(dI/dt)c^{(2)}$	Critical Rate of Current Rise	$(dI/dt)c = 0.1 \text{ V}/\mu\text{s}$ $T_j = 125^\circ\text{C}$ $(dI/dt)c = 10 \text{ V}/\mu\text{s}$ $T_j = 125^\circ\text{C}$ without snubber $T_j = 125^\circ\text{C}$		MIN MIN MIN	6.5 2.9 -	A/ms
$R_{th(j-c)}$	Thermal Resistance Junction-Case	for AC 360° conduction angle			1.4	°C/W
$R_{th(j-a)}$	Thermal Resistance Junction-Ambient				60	°C/W

(1) Minimum  $I_{GT}$  is guaranteed at 5% of  $I_{GT}$  max.

(2) For either polarity of electrode MT2 voltage with reference to electrode MT1.

### PART NUMBER INFORMATION



## LOGIC LEVEL TRIAC

Fig. 1: Maximum power dissipation versus RMS on-state current (full cycle).

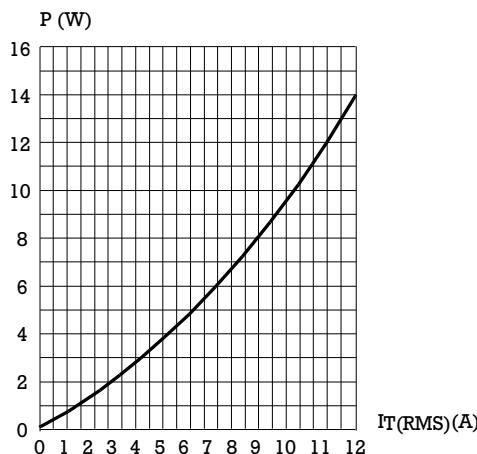


Fig. 3: Relative variation of thermal impedance versus pulse duration.

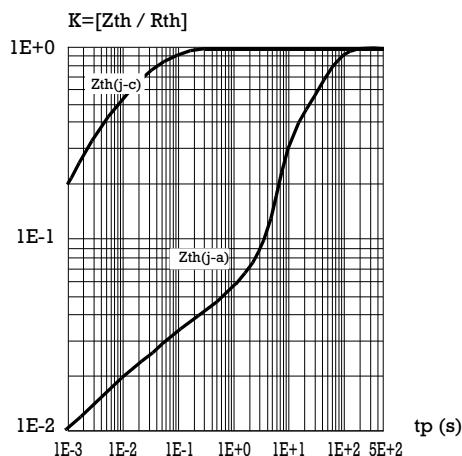


Fig. 5: Surge peak on-state current versus number of cycles

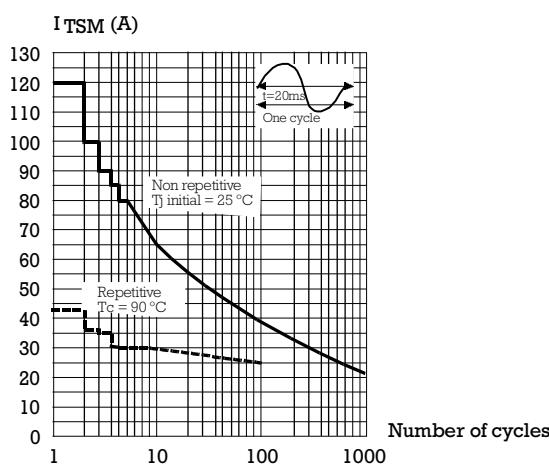


Fig. 2: RMS on-state current versus case temperature (full cycle).

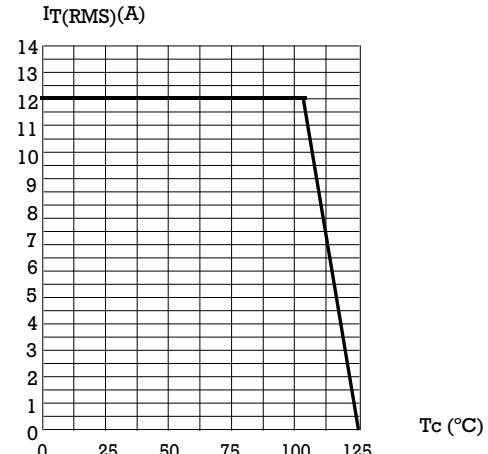


Fig. 4: On-state characteristics (maximum values)

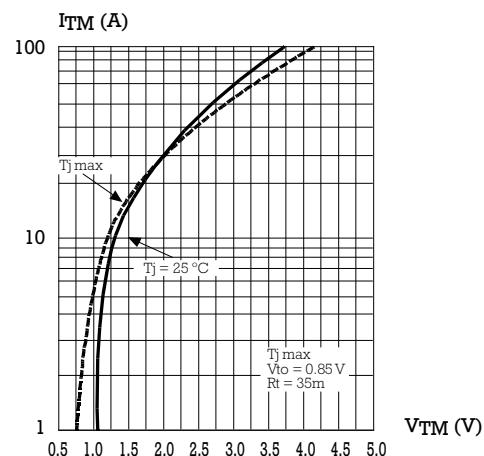
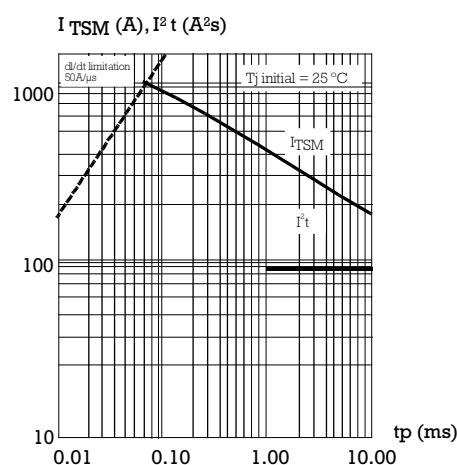
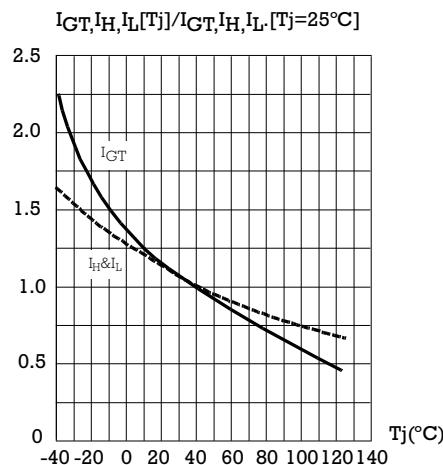


Fig. 6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$ .

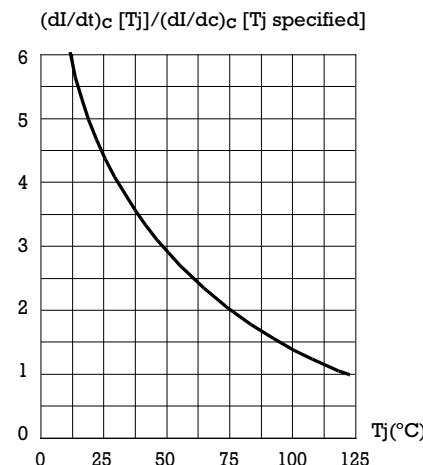


## LOGIC LEVEL TRIAC

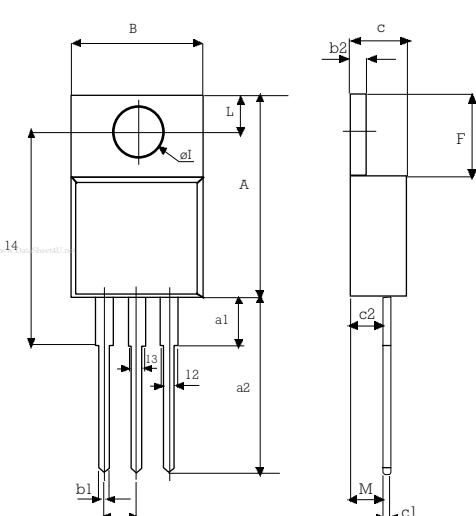
**Fig. 7: Relative variation of gate trigger current, holding current and latching versus junction temperature (typical values)**



**Fig. 8: Relative variation of critical rate of decrease of main current versus junction temperature**



### PACKAGE MECHANICAL DATA TO-220AB (Plastic)



REF.	DIMENSIONS		
	Milimeters		
	Min.	Nominal	Max.
A	15.20		15.90
a1		3.75	
a2	13.00		14.00
B	10.00		10.40
b1	0.61		0.88
b2	1.23		1.32
C	4.40		4.60
c1	0.49		0.70
c2	2.40		2.72
e	2.40		2.70
F	6.20		6.60
I	3.75		3.85
I4	15.80	16.40	16.80
L	2.65		2.95
I2	1.14		1.70
I3	1.14		1.70
M		2.60	